

BZV55 series Voltage regulator diodes Rev. 5 — 26 January 2011

Product data sheet

Product profile 1.

1.1 General description

Low-power voltage regulator diodes in small hermetically sealed glass SOD80C Surface-Mounted Device (SMD) packages. The diodes are available in the normalized E24 \pm 2 % (BZV55-B) and approximately \pm 5 % (BZV55-C) tolerance range. The series consists of 37 types with nominal working voltages from 2.4 V to 75 V.

1.2 Features and benefits

- Non-repetitive peak reverse power dissipation: \leq 40 W
- Total power dissipation: ≤ 500 mW
- Two tolerance series: ±2 % and ±5 %
- Wide working voltage range: nominal 2.4 V to 75 V (E24 range)
- Low differential resistance
- Small hermetically sealed glass SMD package

1.3 Applications

General regulation functions

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
V_{F}	forward voltage	I _F = 10 mA	-	-	0.9	V
P _{ZSM}	non-repetitive peak reverse power dissipation		<u>[1]</u> -	-	40	W

[1] $t_p = 100 \ \mu s$; square wave; $T_j = 25 \ ^\circ C$ prior to surge

2. **Pinning information**

Pin	Description	Simplified outline	Graphic symbol
1	cathode	[1]	
2	anode	k a	1 2 006aaa152

[1] The marking band indicates the cathode.



Voltage regulator diodes

3. Ordering information

Type number	Package	ige	
	Name	Description	Version
BZV55-B2V4 to BZV55-C75[1]	-	hermetically sealed glass surface-mounted package; 2 connectors	SOD80C

[1] The series consists of 74 types with nominal working voltages from 2.4 V to 75 V.

4. Marking

Table 4.	Marking codes	
Type numb	ber	Marking code
BZV55-B2\	/4 to BZV55-C75	marking band

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
I _F	forward current		-	250	mA
I _{ZSM}	non-repetitive peak reverse current		<u>[1]</u> -	see <u>Table 8</u> and <u>9</u>	
P _{ZSM}	non-repetitive peak reverse power dissipation		[1] -	40	W
P _{tot}	total power dissipation	$T_{amb} \le 50 \ ^{\circ}C$	[2] _	400	mW
		$T_{tp} \le 50 \ ^{\circ}C$	[2] _	500	mW
T _{stg}	storage temperature		-65	+200	°C
T _i	junction temperature		-65	+200	°C

[1] $t_p = 100 \ \mu s$; square wave; $T_j = 25 \ ^\circ C$ prior to surge

[2] Device mounted on a ceramic substrate of $10 \times 10 \times 0.6$ mm.

6. Thermal characteristics

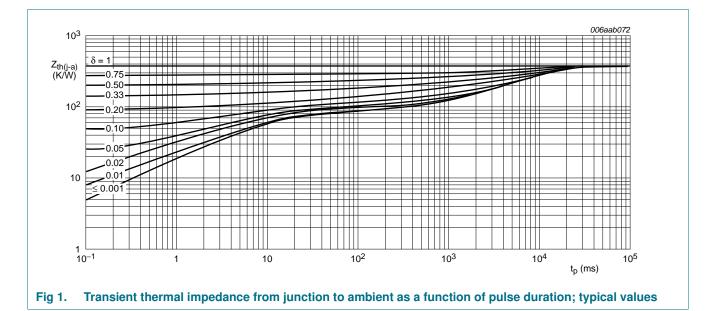
Table 6.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1] -	-	380	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point		-	-	300	K/W

[1] Device mounted on a ceramic substrate of $10 \times 10 \times 0.6$ mm.

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Voltage regulator diodes



7. Characteristics

Table 7.Characteristics

 $T_i = 25 \ ^{\circ}C$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _F	forward voltage	I _F = 10 mA	-	-	0.9	V
I _R	reverse current					
	BZV55-B/C2V4	$V_{R} = 1 V$	-	-	50	μA
	BZV55-B/C2V7	$V_{R} = 1 V$	-	-	20	μA
	BZV55-B/C3V0	$V_{R} = 1 V$	-	-	10	μA
	BZV55-B/C3V3	$V_R = 1 V$	-	-	5	μA
	BZV55-B/C3V6	$V_R = 1 V$	-	-	5	μA
	BZV55-B/C3V9	$V_R = 1 V$	-	-	3	μA
	BZV55-B/C4V3	$V_R = 1 V$	-	-	3	μA
	BZV55-B/C4V7	$V_R = 2 V$	-	-	3	μA
	BZV55-B/C5V1	$V_R = 2 V$	-	-	2	μA
	BZV55-B/C5V6	$V_R = 2 V$	-	-	1	μA
	BZV55-B/C6V2	$V_R = 4 V$	-	-	3	μA
	BZV55-B/C6V8	$V_R = 4 V$	-	-	2	μA
	BZV55-B/C7V5	$V_R = 5 V$	-	-	1	μA
	BZV55-B/C8V2	$V_R = 5 V$	-	-	700	nA
	BZV55-B/C9V1	$V_R = 6 V$	-	-	500	nA
	BZV55-B/C10	$V_R = 7 V$	-	-	200	nA
	BZV55-B/C11	V _R = 8 V	-	-	100	nA
	BZV55-B/C12	V _R = 8 V	-	-	100	nA
	BZV55-B/C13	V _R = 8 V	-	-	100	nA
	BZV55-B/C15 to BZV55-B/C75	$V_{R} = 0.7 V_{Z(nom)}$	-	-	50	nA

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BZV55- xxx	Sel	Worki voltag V _Z (V)	e	r _{dif} (Ω				coeffi S _Z (m	V/K)		Diode capacitance C _d (pF) ^[1]	Non-repetitive peak reverse current I _{ZSM} (A) ^[2]
		l _z = 5		I _Z = 1		I _Z = 5		I _Z = 5				
		Min	Max	Тур	Max	Тур	Max	Min	Тур	Мах	Мах	Max
2V4	В	2.35	2.45	275	600	70	100	-3.5	-1.6	0	450	6.0
	С	2.2	2.6									
2V7	В	2.65	2.75	300	600	75	100	-3.5	-2.0	0	450	6.0
	С	2.5	2.9									
3V0	В	2.94	3.06	325	600	80	95	-3.5	-2.1	0	450	6.0
	С	2.8	3.2									
3V3	В	3.23	3.37	350	600	85	95	-3.5	-2.4	0	450	6.0
	С	3.1	3.5									
3V6	В	3.53	3.67	375	600	85	90	-3.5	-2.4	0	450	6.0
	С	3.4	3.8									
3V9	В	3.82	3.98	400	600	85	90	-3.5	-2.5	0	450	6.0
	С	3.7	4.1									
4V3	В	4.21	4.39	410	600	80	90	-3.5	-2.5	0	450	6.0
	С	4.0	4.6									
4V7	В	4.61	4.79	425	500	50	80	-3.5	-1.4	0.2	300	6.0
	С	4.4	5.0									
5V1	В	5.0	5.2	400	480	40	60	-2.7	-0.8	1.2	300	6.0
	С	4.8	5.4									
5V6	В	5.49	5.71	80	400	15	40	-2.0	1.2	2.5	300	6.0
	С	5.2	6.0									
6V2	В	6.08	6.32	40	150	6	10	0.4	2.3	3.7	200	6.0
	С	5.8	6.6									
6V8	В	6.66	6.94	30	80	6	15	1.2	3.0	4.5	200	6.0
	С	6.4	7.2									
7V5	В	7.35	7.65	30	80	6	15	2.5	4.0	5.3	150	4.0
	С	7.0	7.9									
8V2	В	8.04	8.36	40	80	6	15	3.2	4.6	6.2	150	4.0
	С	7.7	8.7									
9V1	В	8.92	9.28	40	100	6	15	3.8	5.5	7.0	150	3.0
	C	8.5	9.6	_			-	-	-	-		
10	В	9.8	10.2	50	150	8	20	4.5	6.4	8.0	90	3.0
-	C	9.4	10.6			-	-	-				
11	В	10.8	11.2	50	150	10	20	5.4	7.4	9.0	85	2.5
	C	10.4	11.6				_0	U . 1		0.0		
12	В	11.8	12.2	50	150	10	25	6.0	8.4	10.0	85	2.5
	C	11.0	16.6	00	100	10	25	0.0	0.7	10.0	55	2.0

Table 8.Characteristics per type; BZV55-B2V4 to BZV55-C24 $T_i = 25$ °C unless otherwise specified.

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Voltage regulator diodes

BZV55- xxx		Working voltage V _Z (V)			Differential resistance r _{dif} (Ω)			Temp coeffi S _Z (m			Diode capacitance C _d (pF) ^[1]	Non-repetitive peak reverse current	
		l _z = 5 i	mA	l _z = 1	mA	l _z = 5	mA	l _Z = 5	mA			I _{ZSM} (A)[2]	
		Min	Max	Тур	Max	Тур	Max	Min	Тур	Max	Мах	Max	
13	В	12.7	13.3	50	170	10	30	7.0	9.4	11.0	80	2.5	
	С	12.4	14.1										
15	В	14.7	15.3	50	200	10	30	9.2	11.4	13.0	75	2.0	
	С	13.8	15.6										
16	В	15.7	16.3	50	200	10	40	10.4	12.4	14.0	75	1.5	
	С	15.3	17.1										
18	В	17.6	18.4	50	225	10	45	12.4	14.4	16.0	70	1.5	
	С	16.8	19.1										
20	В	19.6	20.4	60	225	15	55	12.3	15.6	18.0	60	1.5	
	С	18.8	21.2										
22	В	21.6	22.4	60	250	20	55	14.1	17.6	20.0	60	1.25	
	С	20.8	23.3										
24	В	23.5	24.5	60	250	25	70	15.9	19.6	22.0	55	1.25	
	С	22.8	25.6										

Table 8. Characteristics per type; BZV55-B2V4 to BZV55-C24 ... continued $T_i = 25$ °C unless otherwise specified.

[1] $f = 1 \text{ MHz}; V_R = 0 \text{ V}$

[2] $t_p = 100 \ \mu s$; square wave; $T_i = 25 \ ^\circ C$ prior to surge

Voltage regulator diodes

BZV55- xxx	Sel	Worki voltag V _Z (V)	e	Diffeı r _{dif} (ମ	rential r 2)	esistar	ice	Temp coeffi S _Z (m			Diode capacitance C _d (pF) ^[1]	Non-repetitive peak reverse current	
		I _Z = 2	mA	I _Z = 0	.5 mA	I _Z = 2	mA	I _Z = 2	mA			I _{ZSM} (A) ^[2]	
		Min	Max	Тур	Max	Тур	Max	Min	Тур	Max	Мах	Max	
27	В	26.5	27.5	65	300	25	80	18.0	22.7	25.3	50	1.0	
	С	25.1	28.9										
30	В	29.4	30.6	70	300	30	80	20.6	25.7	29.4	50	1.0	
	С	28.0	32.0										
33	В	32.3	33.7	75	325	35	80	23.3	28.7	33.4	45	0.9	
	С	31.0	35.0										
36	В	35.3	36.7	80	350	35	90	26.0	31.8	37.4	45	0.8	
	С	34.0	38.0										
39	В	38.2	39.8	80	350	40	130	28.7	34.8	41.2	45	0.7	
	С	37.0	41.0										
43	В	42.1	43.9	85	375	45	150	31.4	38.8	46.6	40	0.6	
	С	40.0	46.0										
47	В	46.1	47.9	85	375	50	170	35.0	42.9	51.8	40	0.5	
	С	44.0	50.0										
51	В	50.0	52.0	90	400	60	180	38.6	46.9	57.2	40	0.4	
	С	48.0	54.0										
56	В	54.9	57.1	100	425	70	200	42.2	52.0	63.8	40	0.3	
	С	52.0	60.0										
62	В	60.8	63.2	120	450	80	215	58.8	64.4	71.6	35	0.3	
	С	58.0	66.0										
68	В	66.6	69.4	150	475	90	240	65.6	71.7	79.8	35	0.25	
	С	64.0	72.0										
75	В	73.5	76.5	170	500	95	255	73.4	80.2	88.6	35	0.2	
	С	70.0	79.0										

Table 9. Characteristics per type; BZV55-B27 to BZV55-C75

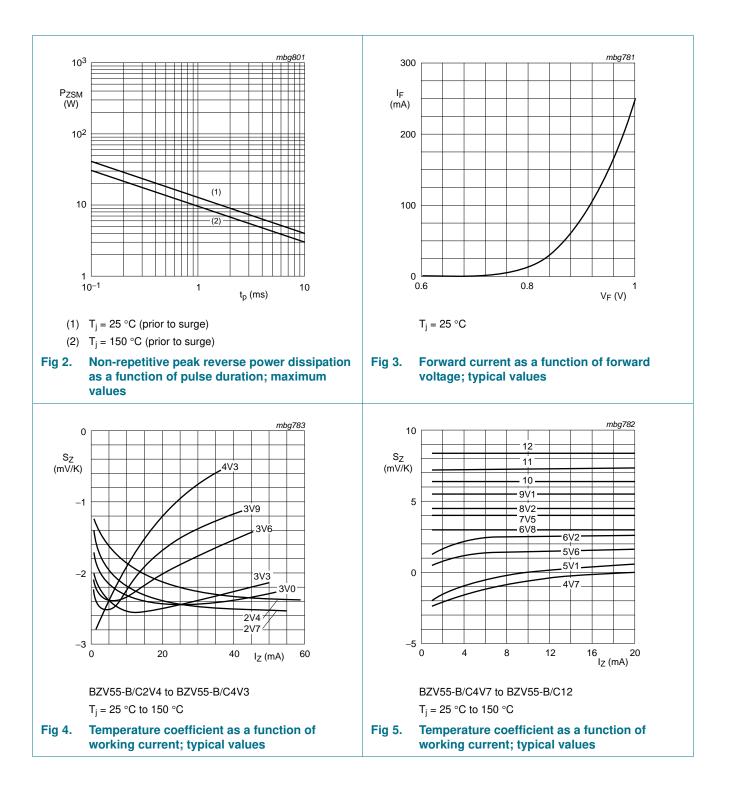
 $[1] \quad f = 1 \ MHz; \ V_R = 0 \ V$

[2] $t_p = 100 \ \mu s$; square wave; $T_i = 25 \ ^\circ C$ prior to surge

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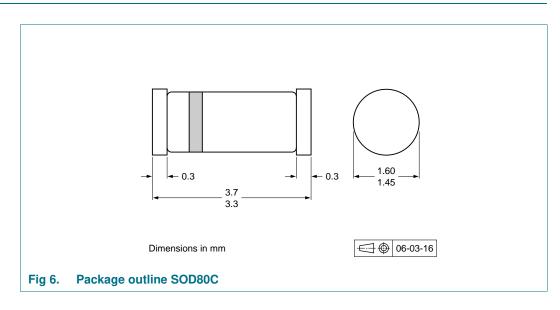
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Voltage regulator diodes

8. Package outline



9. Packing information

Table 10. Packing methods

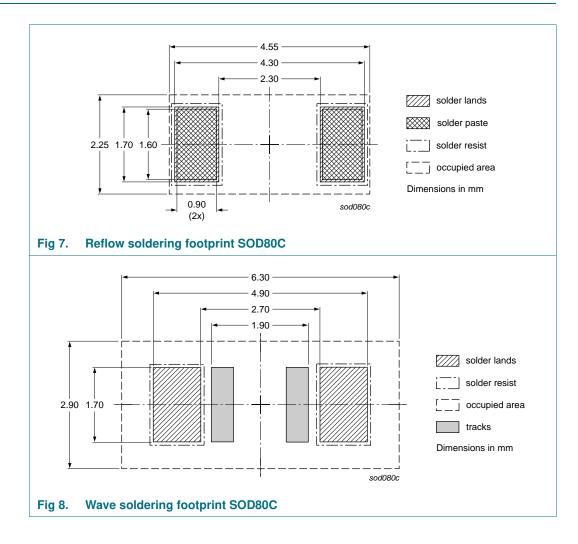
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing	quantity
			2500	10000
BZV55-B2V4 to BZV55-C75	SOD80C	4 mm pitch, 8 mm tape and reel	-115	-135

[1] For further information and the availability of packing methods, see Section 13.

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10. Soldering



Voltage regulator diodes

11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes					
BZV55_SER v.5	20110126	Product data sheet	-	BZV55_SER v.4					
Modifications:	Section 4 "Marking": updated								
	 <u>Table 6 "Thermal characteristics</u>": changed R_{th(j-t)} for R_{th(j-sp)} 								
	<u>Figure 6</u> : superseded by minimized outline drawing								
	 Section 12 "L 	<u>egal information</u> : updated							
BZV55_SER v.4	20070719	Product data sheet	CPCN200508022F	BZV55 v.3					
BZV55 v.3	20020228	Product specification	-	BZV55 v.2					
BZV55 v.2	19990521	Product specification	-	BZV55 v.1					
BZV55 v.1	19960426	Product specification	-	-					

12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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